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in $\text{In}_x\text{Ga}_{1-x}\text{N}$ -Based Nanostructures

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Progress in Nano-Electro Optics IV
Characterization of Nano-Optical Materials and Optical
Near-Field Interactions

Ohtsu, M. (Ed.)

2005, XIV, 208 p., Hardcover

ISBN: 978-3-540-23236-0